



SANYO Semiconductors

## DATA SHEET

# LA72702VA

Monolithic Linear IC  
For US TV  
BTSC Decoder

## Overview

The LA72702VA is a US TV BTSC Decoder.

## Features

- With SIF circuit, alignment-free\* STEREO channel separation.
- \* When Base Band signal input, separation is adjusted by input level.
- Dual Slave address.

## Functions

- IF FM-Demodulator.
- STEREO decoder.
- dbx Noise Reduction.
- STEREO detection.
- STEREO detection sensitivity change function.
- SAP demodulator.
- SAP detection.
- SAP output select 2-levels.
- SAP detection sensitivity change function.

## Specifications

### Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum power supply voltage	V <sub>CC</sub> max		7.0	V
Allowable power dissipation	Pd max	Ta ≤ 70°C *	290	mW
Operating temperature	Topr		-10 to +70	°C
Storage temperature	Tstg		-55 to +150	°C

\* When mounted on a 114.3mm×76.1mm×1.6mm glass epoxy board.

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**Operating Ranges** at  $T_a = 25^{\circ}\text{C}$ 

Parameter	Symbol	Conditions	Ratings	Unit
Recommended operating voltage	$V_{CC}$		5.0	V
Allowable operating voltage range	$V_{CC\text{ op}}$		4.5 to 5.5	V

Caution : Please use this IC under license contract with THAT Corporation, because this IC is included dbx noise reduction system.

**Electrical Characteristics** at  $T_a = 25^{\circ}\text{C}$ ,  $V_{DD} = 5.0\text{V}$ 

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Current dissipation	$I_{CC}$	No signal Inflow current at pin 19, default condition	30	40	50	mA
SIF input level (Reference)	$V_{LIM}$	$f_c = 4.5\text{MHz}$ Deviation MONO (300Hz, Mod = 100%, Pre-emphasis ON) $\rightarrow$ $\pm 25\text{kHz}$	(80)	(90)	(100)	dB $\mu$ V
Base band input level (Reference)	$V_{LIMB}$	100% Modulation MONO(L+R) : 530mVp-p (300Hz, Pre-emphasis ON) SUB(L-R) : 380mVp-p (300Hz, dbx-NR ON), Pilot : 110mVp-p SAP : 300mVp-p (300Hz, dbx-NR ON)				
MONO output level	$V_{OMON}$	$f_m = 1\text{kHz}$ , 100% Mod, 15kHz LPF	-6.5	-5.5	-4.5	dBV
MONO distortion	THDMON	$f_m = 1\text{kHz}$ , 100% Mod, 15kHz LPF		0.15	0.6	%
MONO frequency characteristics	FCM1	$f_m = 3\text{kHz}$ , 30% Mod, Ore-em. ON * Measure ratio from $f_m = 1\text{kHz}$ level.	-2	0	2	dB
MONO S/N ratio	SNM	$S = V_{OMON}$ , $N = 0\%$ Mod, 15kHz LPF	55	65		dB
STEREO output level	$V_{OST}$	$f_m = 1\text{kHz}$ , 100% Mod, 15kHz LPF	-7.0	-5.5	-3.0	dBV
STEREO distortion	THDS	$f_m = 1\text{kHz}$ , 100% Mod, 15kHz LPF		1.0	2.5	%
STEREO frequency characteristics	FCS1	$f_m = 3\text{kHz}$ , 30% Mod, 15kHz LPF * Measure ratio from $f_m = 1\text{kHz}$ level.	-3	0	3	dB
STEREO S/N ratio	SNS	$S = V_{OST}$ , $N = 0\%$ Mod, 15kHz LPF	50	60		dB
STEREO separation 1	STSE1	$f = 300\text{Hz}$ (R/L), 30% Mod, 15kHz LPF	15	25		dB
STEREO separation 2	STSE2	$f = 3\text{kHz}$ (R/L), 30% Mod, 15kHz LPF	15	25		dB
STEREO Detection level-1	$V_{INSD1}$	Except Stereo Detection $\rightarrow$ Stereo Detection * serial control 1 "SENS HI" Pilot (fH) = 15.73kHz * Measure Pilot level.	30	35	40	%
STEREO Detection level-2	$V_{INSD2}$	Except Stereo Detection $\rightarrow$ Stereo Detection * serial control "SENS LO"	40	45	50	%
STEREO Detection hysteresis	HYST	Input Mod. Difference at Stereo/Except Stereo Det. * serial control 1 "SENS HI"	10	20	30	%
SAP output level-1	$V_{OSA1}$	$f_m = 1\text{kHz}$ , 100% Mod, 15kHz LPF * SAP-1 (serial control)	-14.0	-11.0	-8.0	dBV
SAP output level-2	$V_{OSA2}$	$f_m = 1\text{kHz}$ , 100% Mod, 15kHz LPF * SAP-2 (serial control)	-12.0	-9.0	-6.0	dBV
SAP distortion	THDSA	$f_m = 1\text{kHz}$ , 100% Mod, 15kHz LPF		2.5	3.5	%
SAP S/N ratio	SNSA	$S = V_{OSA}$ , $N = 0\%$ Mod, 15kHz LPF	50	60		dB
SAP detection level-1	$V_{INSA1}$	Except SAP $\rightarrow$ SAP Det. * serial control 1 "SENS HI" SAP Carrier = 5fH only * Measure Output level.	10	15	20	%
SAP detection level-2 (Reference)	$V_{INSA2}$	Except SAP $\rightarrow$ SAP Det. * serial control 1 "SENS LO" * Measure Output level.	15	20	25	%
SAP detection hysteresis	HYSA	Input Mod. Difference at SAP/Except SAP Det. * SAP carrier only. * serial control 1 "SENS HI"	2	5	10	%
MODE output MONO	MODMO	Input = MONO : $f = 1\text{kHz}$ , 0% Mod	0.7	1	1.3	V
MODE output SAP	MODSA	Input = SAP : Carrier	1.6	1.9	2.2	V
MODE output STEREO	MODST	Input = STEREO : Pilot	2.5	2.8	3.1	V
MODE output ST + SAP	MODSS	Input = STEREO : Pilot, SAP : Carrier	3.5	3.8	4.2	V

\* Normally measurement condition is Input = SIF mode (90dB $\mu$ V)

\* " Reference " Items are reference levels, their specs are no-guarantee.

unit : mm (typ)

Technical drawing of the 128K1601 memory chip, showing dimensions in millimeters (mm).

**Top View Dimensions:**

- Overall width: 6.5
- Overall height: 6.4
- Pin 1 location: 0.5 from left edge, 0.22 from bottom edge.
- Pin 24 location: 0.5 from left edge, 0.22 from bottom edge.
- Pin 13 location: 0.5 from right edge, 0.22 from bottom edge.
- Pin 12 location: 0.5 from right edge, 0.22 from bottom edge.
- Pin 1 location: 0.5 from left edge, 0.22 from bottom edge.
- Pin 24 location: 0.5 from left edge, 0.22 from bottom edge.
- Pin 13 location: 0.5 from right edge, 0.22 from bottom edge.
- Pin 12 location: 0.5 from right edge, 0.22 from bottom edge.

**Side View Dimensions:**

- Chip thickness: 0.15
- Pin height: 0.5

**Detail View Dimensions:**

- Pin pitch: 0.1
- Pin height: 1.3
- Maximum pin height: 1.5max

SANYO : SSOP24(225mil)

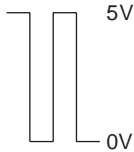
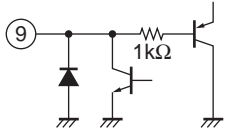
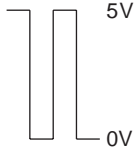
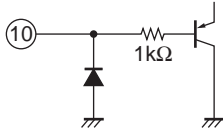
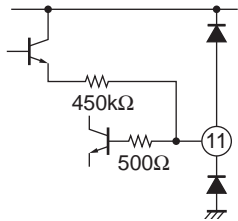
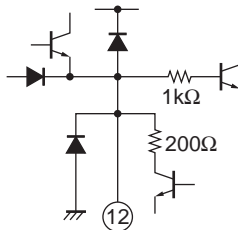
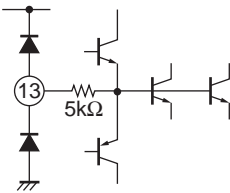
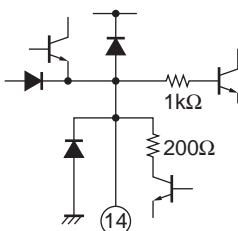
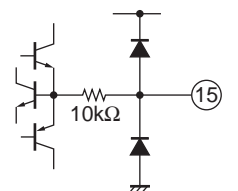
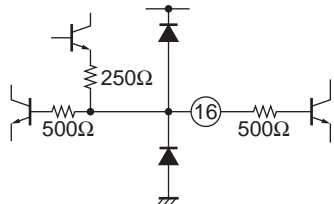
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SLAVE ADDRESS = 80h (1000 000*) : Pin8 = OPEN
SLAVE ADDRESS = 84h (1000 010*) : Pin8 = H
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## Pin Functions

Pin No.	Pin Name	Function	DC voltage AC level	Equivalent Circuit
1	PCPLDET	Pilot level detect For Stero Detection	DC : 2.4V	
2	PC DC IN	AC coupling (Input)	DC : 2.4V AC : 2.4Vp-p	
3	PC DCOUT	AC coupling (Output)	DC : 2.4V AC : 2.4Vp-p	
4	PISIF	Signal input Common input at SIF, Baseband	DC : 3.7V	
5	PC FIL	SIF offset cancel	DC : 2.6V	
6	GND			
7	CSAPDET	SAP carrier level detect For SAP detection	DC : 2.8V	
8	ADDSEL	Slave Address change control  OPEN/GND : 80h 5V : 84h	DC : 0V	

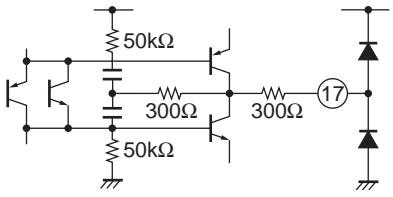
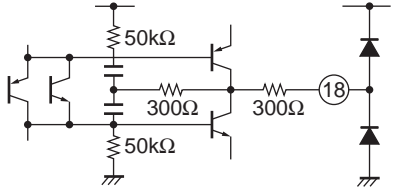
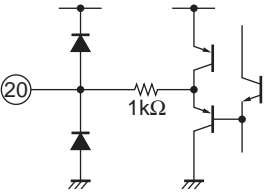
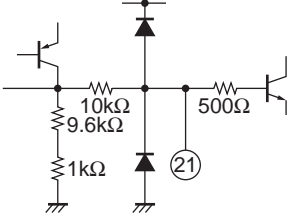
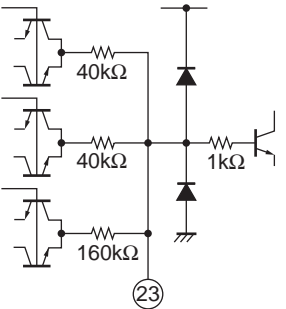
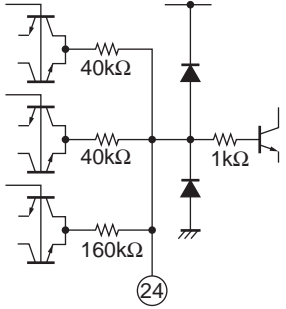
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Pin No.	Pin Name	Function	DC voltage AC level	Equivalent Circuit
9	SDA	Serial data input	 5V 0V	
10	SCL	Serial clock input	 5V 0V	
11	PC DBXIN	Offset cancel Feedback filter	DC : 1.6V	
12	PCDETSPE	Spectral band RMS detect	DC : 2.3V	
13	PCTIMSPE	dbx spectral detect	DC : 2.4V	
14	PCTNWID	dbx RMS detect (wide band)	DC : 2.4V	
15	PCSPECIN	dbx main signal V/I convert filter	DC : 2.4V	
16	PC KE6B	Offset cancel filter	DC : 2.4V AC : 220mVp-p	

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Pin No.	Pin Name	Function	DC voltage AC level	Equivalent Circuit
17	PORCH	Line out R	DC : 2.4V AC : 1.4Vp-p	
18	POLCH	Line out L	DC : 2.4V AC : 1.4Vp-p	
19	V <sub>CC</sub>			
20	POLED	MONO = 3.0V SAP = 2.0V STEREO = 1.0V STEREO + SAP = 3.8V Mode out	DC : See Right AC Test only	
21	PCREG	Reference Voltage	DC : 2.4V	
23	PCPLC	Pilot level detect For Pilot canceller	DC : 2.4V	
24	PCPLDET	Pilot level detect For ST PLL filter	DC : 2.4V	

## I<sup>2</sup>C BUS serial interface specification

### (1) Data Transfer Manual

This IC adopts control method(I<sup>2</sup>C-BUS) with serial data, and controlled by two terminals which called SCL(serial clock) and SDA (serial data).At first, set up<sup>\*1</sup> the condition of starting data transfer, and after that, input 8 bit data to SDA terminal with synchronized SCL terminal clock. The order of transferring is first, MSB (the Most Scale of Bit), and save the order. The 9th bit takes ACK (Acknowledge) period, during SCL terminal takes 'H', this IC pull down the SDA terminal. After transferred the necessary data, two terminals lead to set up and of<sup>\*2</sup> data transfer stop condition, thus the transfer comes to close.

\*1 Defined by SCL rise down SDA during 'H' period.

\*2 Defined by SCL rise up SDA during 'H' period.

### (2) Transfer Data Format

After transfer start condition, transfers slave address (1000 000\*) to SDA terminal, control data, then, stop condition (See figure 1).

Slave address is made up of 7bits, 8th bit<sup>\*3</sup> shows the direction of transferring data, if it is 'L' takes write mode (As this IC side, this is input operation mode), and in case of 'H' reading mode (As this IC side, this is output operation mode). Data works with all of bit, transfer the stop condition before stop 8bit transfer, and to stop transfer, it will be canceled the transfer dates.

\*3 It is called R/W bit.

Fig.1 DATA STRUCTURE "WRITE" mode

START Condition	Slave Address	R/W <sub>L</sub>	ACK	Control data	ACK	STOP condition
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Fig.2 DATA STRUCTURE "READ" mode

START condition	Slave Address	R/W <sub>H</sub>	ACK	Internal Data *	ACK	STOP condition
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\* Output data as follows ;

bit8 is result of STERO DET (H : STEREO), bit7 is result of SAP DET (H : SAP),

bit6 to bit1 are fixed to 'L'

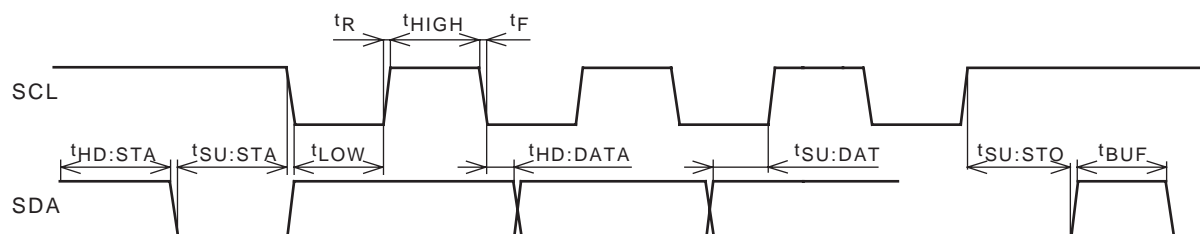
### (3) Initialize

This IC is initialized for circuit protection. Initial condition is "0 (All bits) ".



**I<sup>2</sup>C Timing Specifications**

Parameter	Symbol	min	max	unit
LOW level input voltage	$V_{IL}$	-0.5	1.5	V
HIGH level input voltage	$V_{IH}$	3.0	5.5	V
LOW level output current	$I_{OL}$		3.0	mA
SCL clock frequency	$f_{SCL}$	0	100	kHz
Set-up time for a repeated START condition	$t_{SU : STA}$	4.7		$\mu s$
Hold time START condition. After this period, the first clock pulse is generated	$t_{HD : STA}$	4.0		$\mu s$
LOW period of the SCL clock	$t_{LOW}$	4.7		$\mu s$
Rise time of both SDA and SDL signals	$t_R$	0	1.0	$\mu s$
HIGH period of the SCL clock	$t_{HIGH}$	4.0		$\mu s$
Fall time of both SDA and SDL signals	$t_F$	0	1.0	$\mu s$
Data hold time :	$t_{HD : DAT}$	0		$\mu s$
Data set-up time	$t_{SU : DAT}$	250		ns
Set-up time for STOP condition	$t_{SU : STO}$	4.0		$\mu s$
BUS free time between a STOP and START condition	$t_{BUF}$	4.7		$\mu s$

**Definition of timing**

**I<sup>2</sup>C Control Table**

Grp-1 (Normally use : group-1 only)

	D8	D7	D6	D5	D4	D3	D2	D1	Condition
*							0	0	Stereo
							0	1	SAP
							1	0	Both
							1	1	MUTE
*						0			Normal (Auto det)
						1			Forced Mono
*					0				SAP SENS LO
					1				SAP SENS HI
*				0					Stereo SENS LO
				1					Stereo SENS HI
*			0						SAP Level-1
			1						SAP Level-2
*		0							SIF mode
		1							Base Band mode
*	0								Fix
	1								Prohibit (TEST MODE)

\* : Shows Initial condition

**Read out data**

D8	D7	D6	D5	D4	D3	D2	D1	Condition
		0	0	0	0	0	0	Fixed
	0							Normal
	1							SAP det
0								Normal
1								Stereo det

**Test mode condition**

When STOP condition transform at Grp-1 data-end, controlled NORMAL mode.

Grp-2 (Only test condition : Normally, this data is no-need)

D8	D7	D6	D5	D4	D3	D2	D1	Condition/Monitor position
0	0	0	0	0	0	0	0	Normal (Usually, Fixed)
0	0	0	0	0	0	0	1	TEST-1 SIF output
0	0	0	0	0	0	1	0	TEST-2 SAP BPF
0	0	0	0	0	0	1	1	TEST-3 (reserved)
0	0	0	0	0	1	0	0	TEST-4 ST VCO
0	0	0	0	0	1	0	1	TEST-5 (reserved)
0	0	0	0	0	1	1	0	TEST-6 SAP monitor
0	0	0	0	0	1	1	1	TEST-7 ST monitor
0	0	0	0	1	0	0	0	TEST-8 Pilot cancel monitor
0	0	0	0	1	0	0	1	TEST-9 dbx 2.19k LPF
0	0	0	0	1	0	1	0	TEST-10 dbx 408 LPF
0	0	0	0	1	0	1	1	TEST-11 dbx DET 10k LPF
0	0	0	0	1	1	0	0	TEST-12 dbx SPEC 7.6k LPF
0	0	0	0	1	1	0	1	TEST-13 dbx SPEC output
0	0	0	0	1	1	1	0	TEST-14 (reserved)
0	0	0	0	1	1	1	1	TEST-15 dbx 2.09k LPF

Blanc Bit are no-care

## Mode Condition

SIGNAL	Detection		control			Mode Condition	output		
	ST	SAP	System	Mute	Mono		18 L ch	17 R ch	20 Mode
STEREO + SAP	ST DET	SAP DET	STEREO	L : NORM	L : NORM	STEREO	L	R	3.8V
			BOTH	L : NORM	L : NORM	MULTI	LR	SAP	
			SAP	L : NORM	L : NORM	SAP	SAP	SAP	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R	
			BOTH	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
STEREO	ST DET		STEREO	L : NORM	L : NORM	STEREO	L	R	3.0V
			BOTH	L : NORM	L : NORM	STEREO	L	R	
			SAP	L : NORM	L : NORM	STEREO	L	R	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R	
			BOTH	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
MONO + SAP		SAP DET	STEREO	L : NORM	L : NORM	MONO	L+R	L+R	2.0V
			BOTH	L : NORM	L : NORM	MULTI	L+R	SAP	
			SAP	L : NORM	L : NORM	SAP	SAP	SAP	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R	
			BOTH	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
MONO			STEREO	L : NORM	L : NORM	MONO	L+R	L+R	1.0V
			BOTH	L : NORM	L : NORM	MONO	L+R	L+R	
			SAP	L : NORM	L : NORM	MONO	L+R	L+R	
			STEREO	L : NORM	H : MONO	MONO	L+R	L+R	
			BOTH	L : NORM	H : MONO	MONO	L+R	L+R	
			SAP	L : NORM	H : MONO	MONO	L+R	L+R	
*	*	*	*	H : MUTE	*	MUTE	OFF	OFF	Each

\* : no problem

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